

## ***Supporting information***

### **A flexible and self-formed sandwich structure strain sensor based on AgNW decorated electrospun fibrous mats with excellent sensing capability and good oxidation inhibition property**

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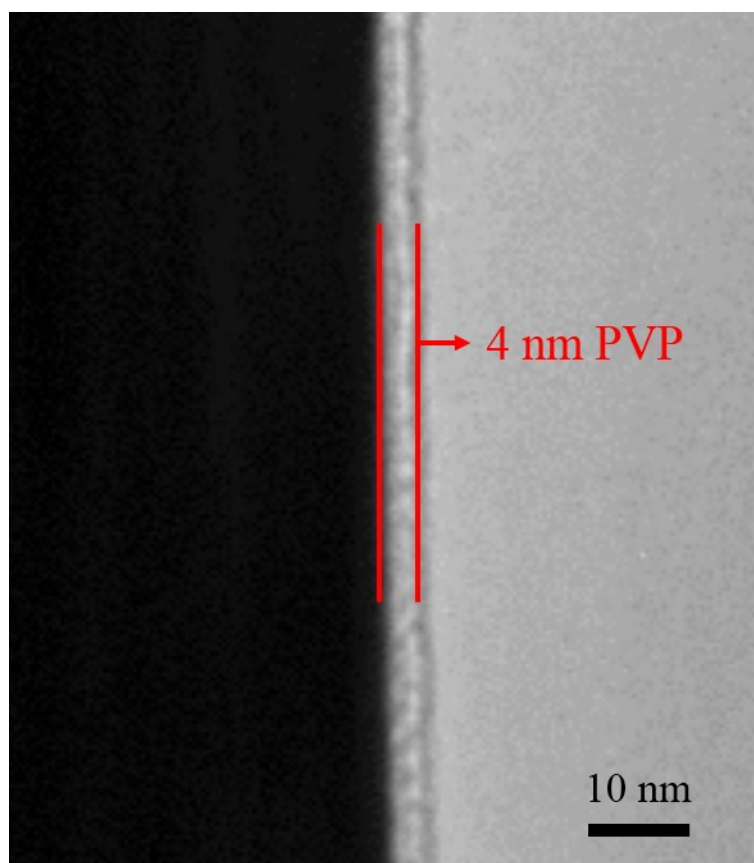
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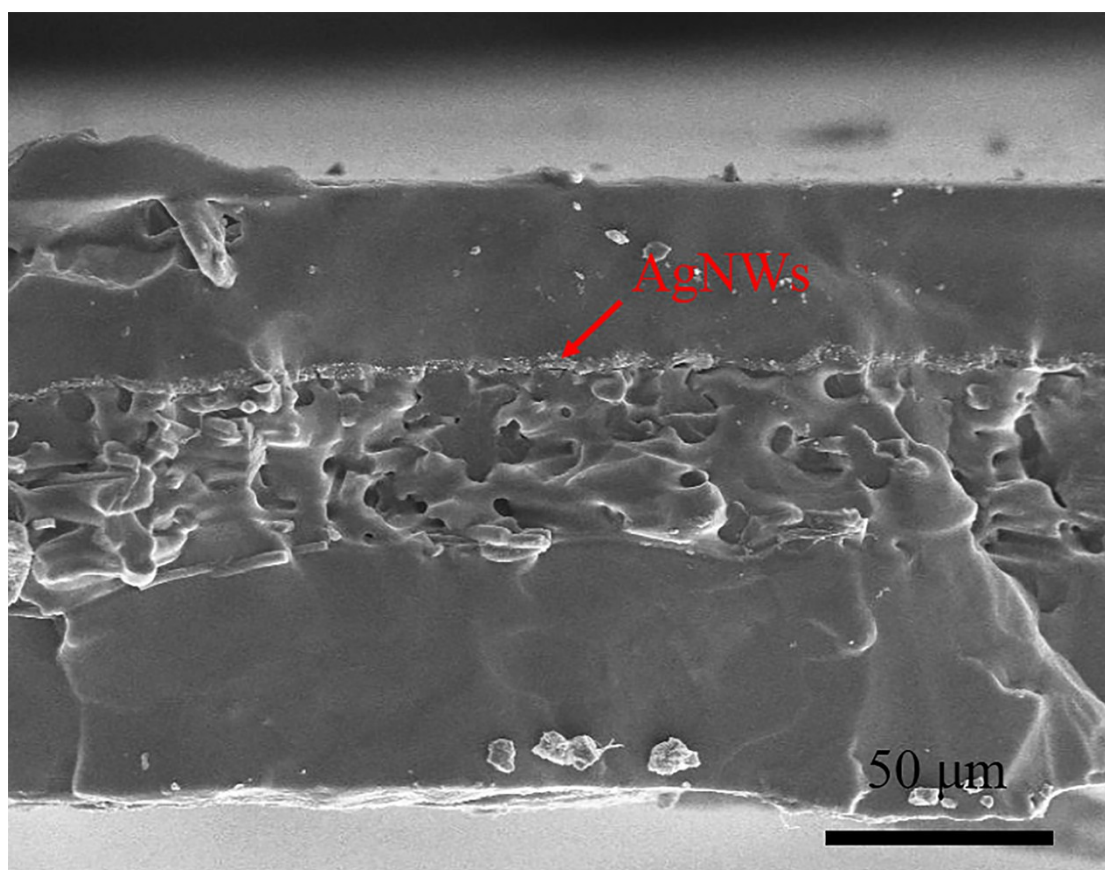
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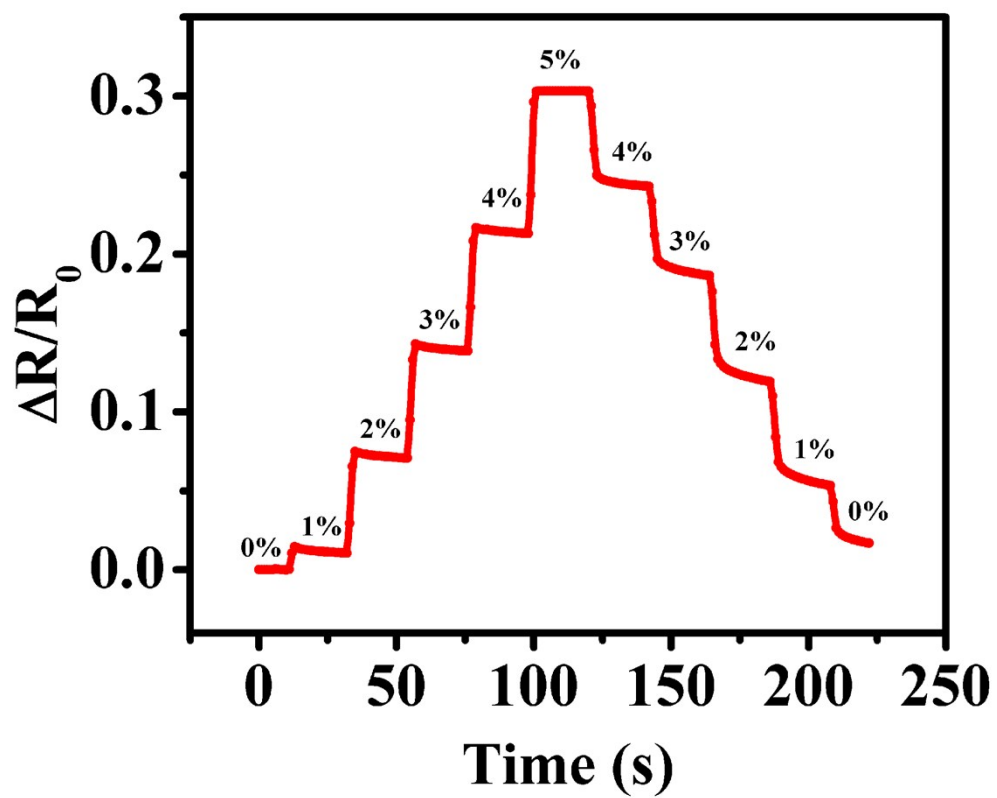
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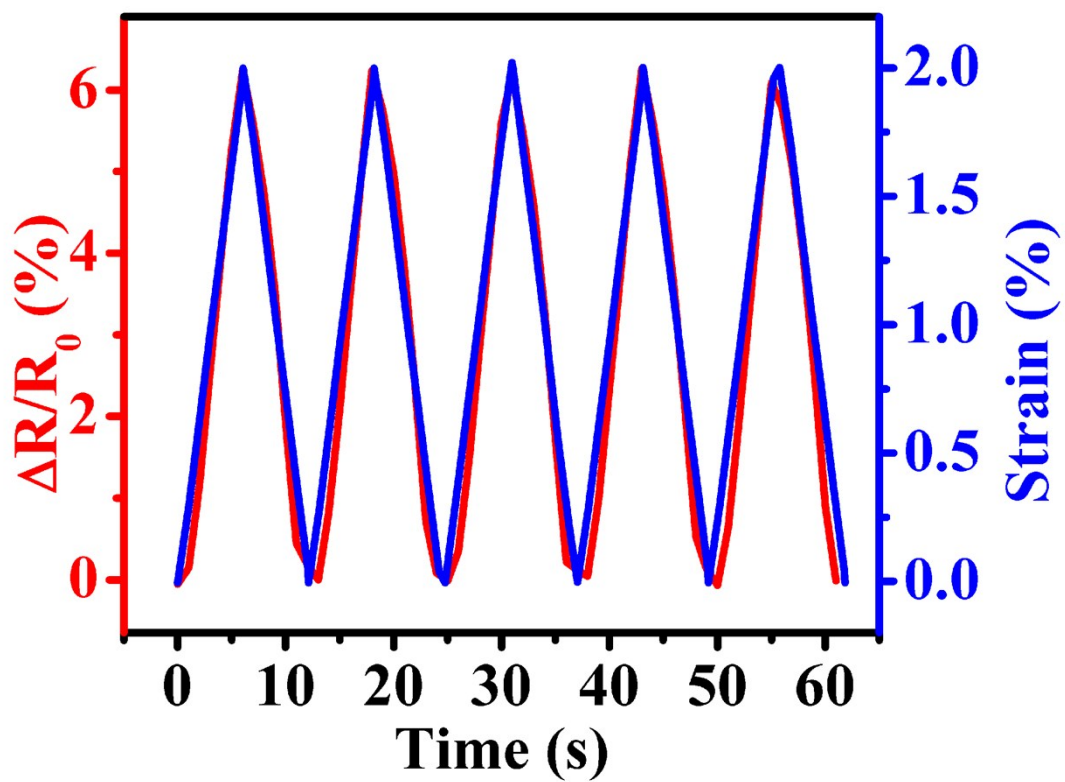
**Fig. S1.** TEM image of as-prepared AgNWs, showing 4 nm PVP absorbed on the surface.



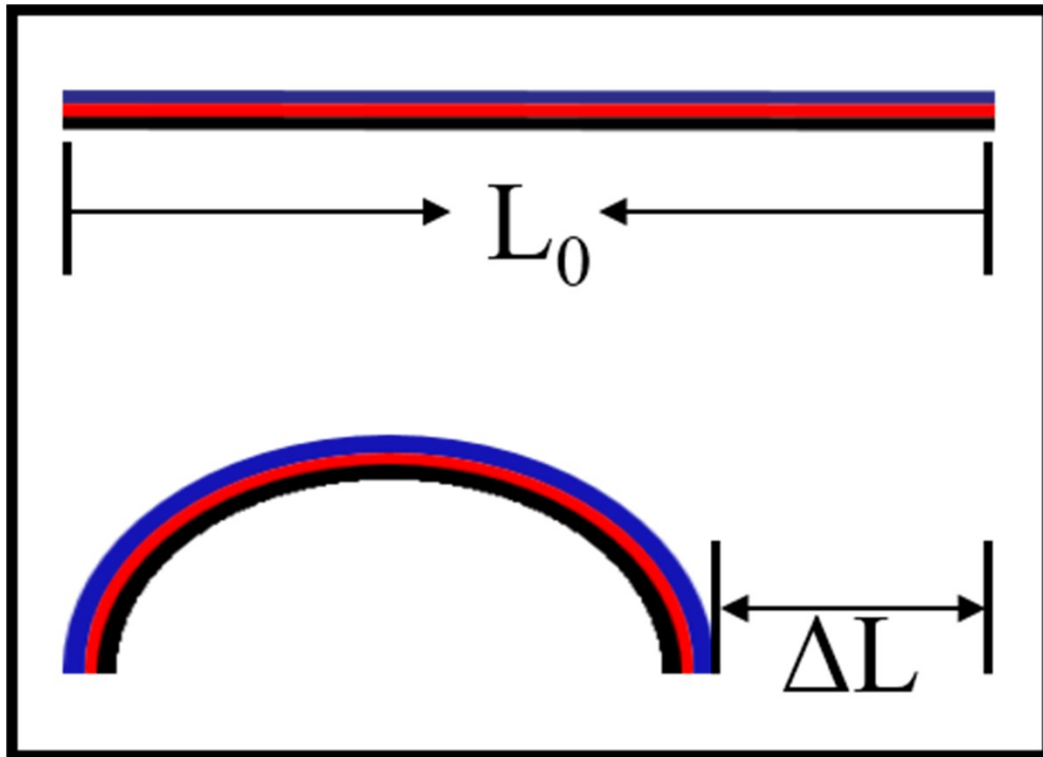
**Fig. S2.** Cross-sectional SEM image of an ATP strain sensor with self-formed sandwich structure with a higher magnification.



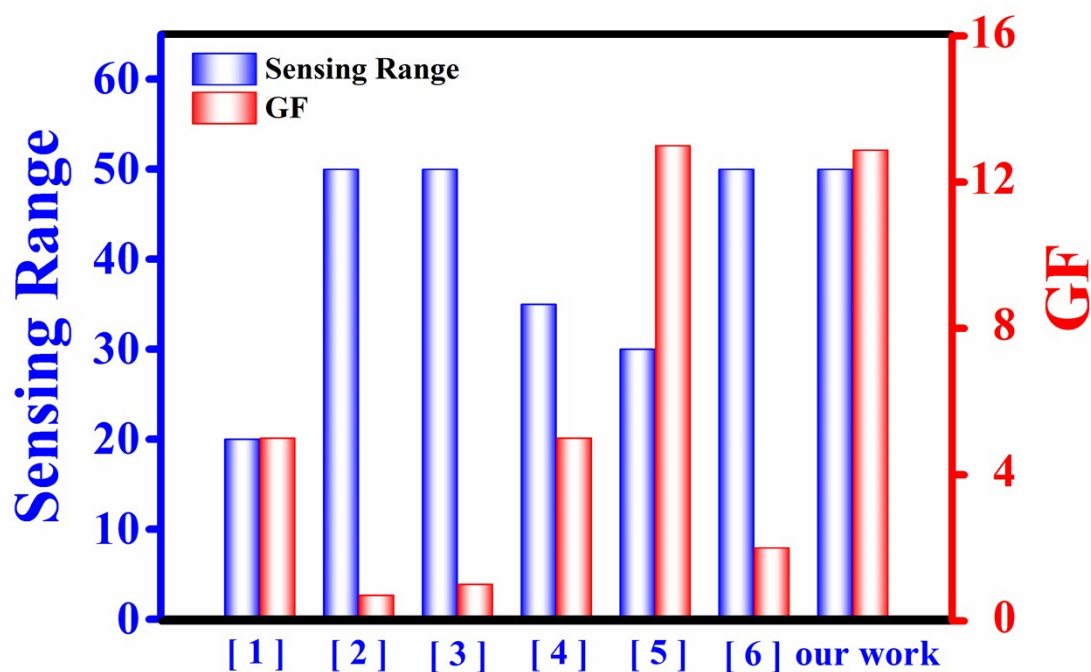
**Fig. S3.** A cycle of strain from 0% to 5% then back to 0%, being held at different strains.



**Fig. S4.** Cycling test of ATP strain sensor; its relative resistance changes synchronously with the strain.



**Fig. S5.** Schematic illustration of bending an ATP strain sensor.



**Fig. S6.** Comparison on GF and sensing range of ATP strain sensors with previous works.

## References

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